# International **IOR** Rectifier

# IR3313(S)PbF

# **PROGRAMMABLE CURRENT SENSE HIGH SIDE SWITCH**

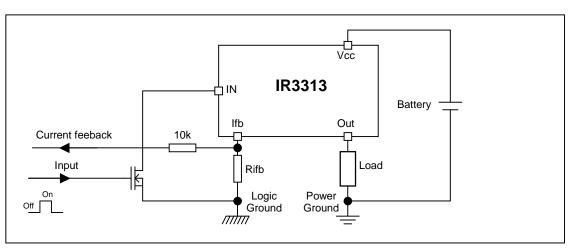
## Features

- Load current feedback
- Programmable over current shutdown
- Active clamp
- ESD protection
- Input referenced to Vcc
- Over temperature shutdown
- Reverse battery protection

## Description

The IR3313(S)PbF is a fully protected 4 terminals high side switch. The input signal is referenced to Vcc. When the input voltage Vcc - Vin is higher than the specified threshold, the output power Mosfet is turned on. When the Vcc - Vin is lower than the specified Vil threshold, the output Mosfet is turned off. A current proportional to the power Mosfet current is sourced to the Ifb pin. Over current shutdown occurs when Vst-Vin > 4.5V. The current shutdown threshold is adjusted by selecting the proper RIfb. Either over current and over temperature latches off the switch. The device is reset by pulling the input pin high. Other integrated protections (ESD, reverse battery, active clamp) make the switch very rugged in automotive environment.

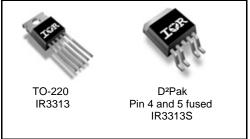
## **Typical Connection**



# Product Summary

Rds(on)	7 m $\Omega$ max.
Vcc op.	6 to 32V
Current Ratio	8800
Prog. Ishutdow	n 10 to 90A
Vclamp	40V

### Packages



#### **Absolute Maximum Ratings**

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are referenced to Vcc lead. (Tambient=25°C unless otherwise specified).

Symbol	Parameter	Min.	Max.	Units
Vcc-Vin	Maximum Vcc voltage	-16	37	
Vcc-Vin cont.	Maximum continuous Vcc voltage	-16	32	V
Vcc-Vfb	Maximum Ifb voltage	-16	33	v
Vcc-Vout	Maximum output voltage	-0.3	37	
lds cont.	Maximum body diode continuous current Rth=60°C/W (1)	—	2.8	А
lds pulsed	Maximum body diode pulsed current (1)	—	100	~
Pd	Maximum power dissipation Rth=60°C/W	—	2	W
ESD1	Electrostatic discharge voltage (Human body) C=100pF, R=1500 $\Omega$	—	4	kV
ESD2	Electrostatic discharge voltage (Machine Model) C=200pF,R=0Ω	_	0.5	ĸv
Tj max.	Max. storage & operating temperature junction temperature	-40	150	°C
Min Rfb	Minimum on the resistor on Ifb pin	0.3	_	kΩ
lfb max.	Max. Ifb current	-50	50	mA

(1) Limited by junction temperature. Pulsed is also limited by wiring

### **Thermal Characteristics**

Symbol	Parameter	Тур.	Max.	Units
Rth1	Thermal resistance junction to ambient D <sup>2</sup> -Pak Std footprint	60	_	
Rth2	Thermal resistance junction to case D <sup>2</sup> -Pak	0.7	_	°C/W
Rth2	Thermal resistance junction to case TO220	0.7	_	

#### **Recommended Operating Conditions**

These values are given for a quick design. For operation outside these conditions, please consult the application notes.

Symbol	Parameter	Min.	Max.	Units
lout	Continuous output current			
	Tambient=85°C, Rth=5°C/W, Tj=125°C		23	Α
	Tambient=85°C, Rth=60°C/W, Tj=125°C	_	7	
Rifb	Recommended Ifb resistor (2)(3)	0.3	3.5	kΩ
Pulse min.	Minimum turn-on pulse width	1	_	ms
Fmax.	Maximum operating frequency	_	200	Hz

2) If Rifb is too low, the device can be damaged.

3) If Rifb is too high, the device may not switch on.

### **Protection Characteristics**

Tj=25°C,	Rifb=500 to 3.5kΩ

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
Vifb-Vin@Isd	Over-current shutdown threshold	4	4.7	5.6	V	
Tsd	Over temperature threshold		165		°C	See fig. 5
OV	Over voltage protection (not latched)	33	35	39	V	
lsdf	Fixed over current shutdown	90	120	140	٨	Vifb <vifb-vin@isd< td=""></vifb-vin@isd<>
lsd_1k	Programmable over current shutdown 1k	30	40	50	A	Rifb=1kΩ
Treset	Time to reset protection		50	500		See fig. 5
Min. pulse	Min. pulse width (no WAIT state)	200	400	1200	μs	
WAIT	WAIT function timer	0.4	1	2	ms	See fig. 4 and 5
Rds(on) rev.	Reverse battery On state resistance	4	6.7	10	mΩ	Vcc-Vin=-14V,
						lout=30A

## **Static Electrical Characteristics**

Tj=25°C, Vcc=14V (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
Vcc op.	Operating Voltage range	6	_	32	V	
Icc off	Supply leakage current	—	1.5	5	μA	Vin=Vcc, Vcc-Vout=14V Vcc-Vifb=14V
lin, on	On state IN positive current	1.5	3	6	mA	Vcc-Vin=14V
Vih	High level Input threshold voltage (4)	_	5.4	6.2		
Vil	Low level Input threshold voltage (4)	4	4.9	5.8	V	
Vhyst	Input hysteresis Vih-Vil	0.2	0.4	1	]	
lout	Drain to source leakage current	—	1.2	5	μA	Vin=Vcc, Vcc-Vifb=0V, Vcc-Vout=14V
Rds(on)	On state resistance (5) Tj=25°C	4	5.5	7		lout=30A, Vcc-Vin=14V
	On state resistance (5) Tj=25°C	4	6	10	mΩ	lout=17A, Vcc-Vin=6V
	On state resistance (5)(6) Tj=150°C	7	10.5	13.5	1	Iout=30A, Vcc-Vin=14V
V clamp1	Vcc to Vout clamp voltage 1	36	39		V	lout=50mA
V clamp2	Vcc to Vout clamp voltage 2	_	40	43	v	lout=30A

(4) Input thresholds are measured directly between the input pin and the tab. Any parasitic resistance in common between the load current path and the input signal path can significantly affect the thresholds.

(5) Rdson is measured between the tab and the Out pin, 5mm away from the package.

(6) Guaranteed by design

## **Switching Electrical Characteristics**

Vcc=14V, Resistive load=0.5Ω, Tj=25°C

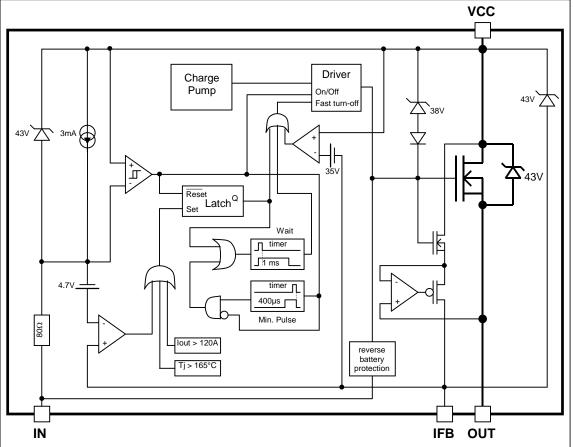
Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
Tdon	Turn on delay time to 10% Vcc	8	32	80		
Tr1	Rise time to Vcc-Vout=5V	3	16	40	μs	
Tr2	Rise time to Vcc-Vout=0.1Vcc	10	40	100		
Eon	Turn on energy	-	4.5	—	mJ	See figure 2
Tdoff	Turn off delay time	20	80	200	110	
Tf	Fall time to Vout=10% of Vcc	8	32	80	μs	
Eoff	Turn off energy	—	2	_	mJ	

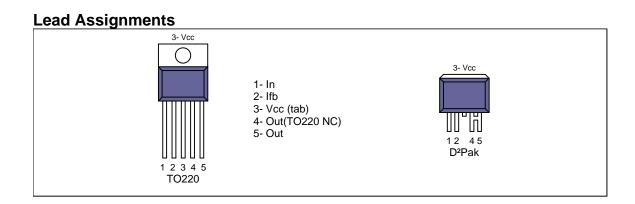
### **Current Sense Characteristics**

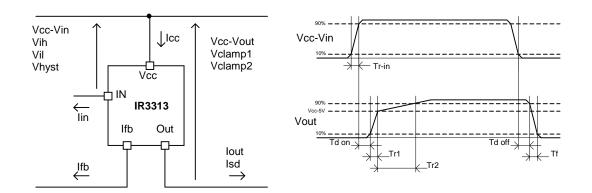
Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
Ratio	I Load/lifb current ratio	7,500	8,800	9,950		Tj=25°C, Rfb=500Ω,
						lout=60A
Ratio_TC	I Load/lifb variation aver temperature(6)	-5		+5	%	Tj=-40°C to 150°C
Offset	Load current diagnostic offset	-0.22	0	+0.2	А	lout=2A
Trst	Ifb response time (low signal)	_	1		μs	90% of the lout step

## **Functional Block Diagram**

All values are typical



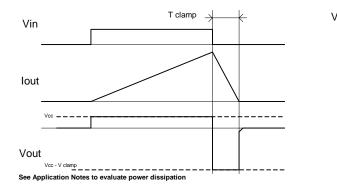




#### Figure 1 – Voltages and current definitions

#### Figure 2 – Switching time definitions

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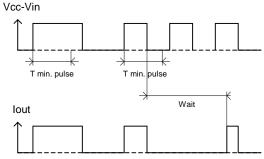
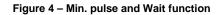


Figure 3 – Active clamp waveforms



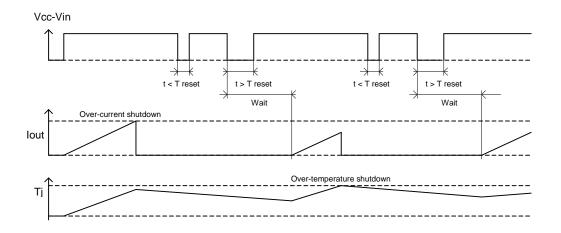
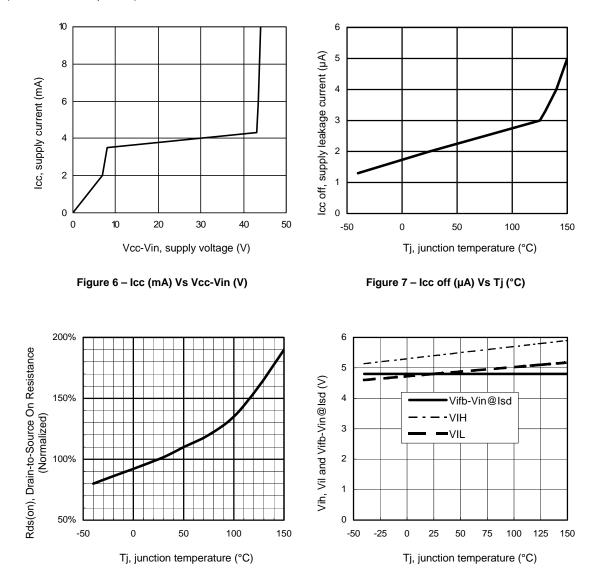


Figure 5 – Protection Timing Diagrams

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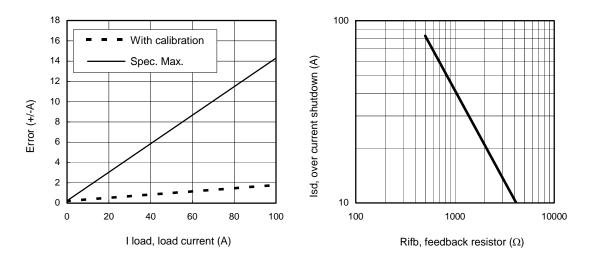


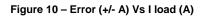
All curves are typical characteristics. Operation in hatched areas is not recommended. Tj=25°C, Rifb=500ohm, Vcc=14V (unless otherwise specified).

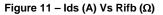
Figure 8 - Normalized Rds(on) (%) Vs Tj (°C)

Figure 9 – Vih, Vil and Vifb-Vin@lsd (V) Vs Tj (°C)

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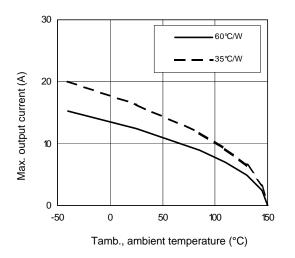


Figure 12 – Max. lout (A) Vs Tamb. (°C)

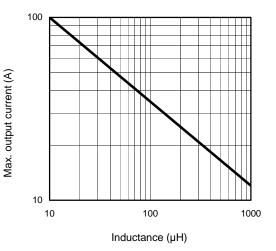
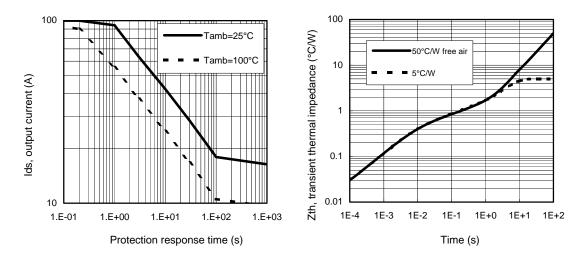


Figure 13 – Max. lout (A) Vs inductance (µH)

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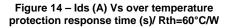
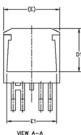
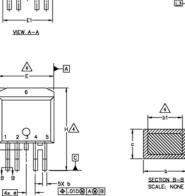


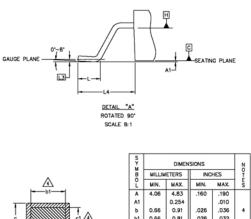
Figure 15 – Transient thermal impedance (°C/W) Vs time (s)

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## Case Outline 5 Leads - D2PAK – Automotive Q100 PbF MSL1 qualified





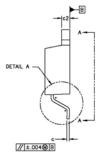






Y		N						
B O L	MILLIM	ETERS	INC	INCHES				
Ľ	MIN.	MAX.	MIN.	MAX.	NOTES			
A	4.06	4.83	.160	.190				
A1		0.254		.010				
ь	0.66	0.91	.026	.036	4			
Ь1	0.66	0.81	.026	.032				
c	0.38	0.74	.015	.029				
c1	0.38	0.58	.015	.023	4			
c2	1.14	1.65	.045	.065				
D	8.51	9.65	.335	.380	3			
D1	6.86		.270					
E	9.65	10.67	.380	.420	3			
E1	6.22		.245					
e	1.70	BSC	.067	BSC				
н	14.73	15.49	.580	.609				
L	1.14	1.39	.045	.055				
L1		1.65		.065				
L2	1.27	1.78	.050	.070				
L3	0.25	BSC	.010	BSC				
L4	4.78	5.28	.188	.208				
m	17.78		.700					
m1	8.89		.350					
n	11.43		.450					
0	1.93		.076					
P	3.81		.150					
R	0.51	0.71	.020	.028				

FOOT PRINT SCALE 2:1



NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994

2. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].

3. DIMENSION D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.127 [.005"] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY.

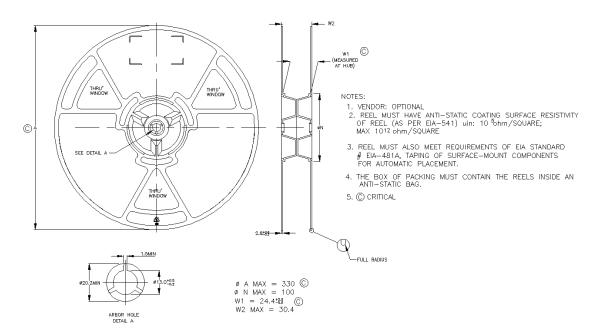
ADIMENSION 51 AND c1 APPLY TO BASE METAL ONLY.

5. CONTROLLING DIMENSION: MILLIMETERS

6. LEADS AND DRAIN ARE PLTED WITH 100% Sn

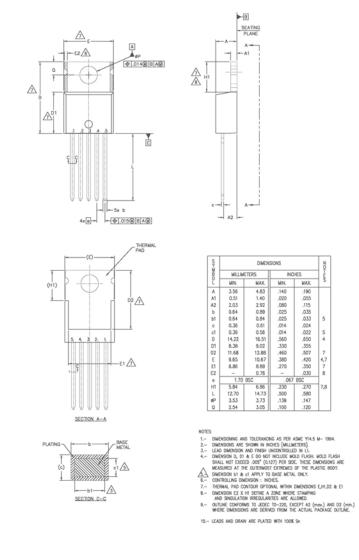
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### Tape & Reel 5 Lead - D2PAK (SMD220)

### Case Outline 5 Leads - TO220 - Automotive Q100 PbF qualified



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IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245 Tel: (310) 252-7105 Data and specifications subject to change without notice. D2Pak is MSL1 qualified. This product has been designed and qualified for the Automotive [Q100] market. 08/03/2010